COMPLIANT

HALOGEN FREE

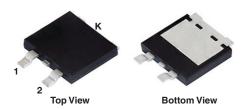


Vishay General Semiconductor

Dual High-Voltage TMBS® (Trench MOS Barrier Schottky) Rectifier

Ultra Low $V_F = 0.40 \text{ V}$ at $I_F = 5.0 \text{ A}$







DESIGN SUPPORT TOOLS AVAILABLE



| PRIMARY CHARACTERISTICS | | | | |
|---|-----------------|--|--|--|
| I _{F(AV)} | 2 x 30 A | | | |
| V _{RRM} | 100 V | | | |
| I _{FSM} | 320 A | | | |
| V _F at I _F = 30 A (T _A = 125 °C) | 0.70 V | | | |
| T _J max. | 175 °C | | | |
| Package | SMPD (TO-263AC) | | | |
| Circuit configuration | Common cathode | | | |

FEATURES

- Trench MOS Schottky technology
- Very low profile typical height of 1.7 mm
- · Ideal for automated placement
- · Low forward voltage drop, low power losses
- · High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified available:
 - Automotive ordering code: base P/NHM3
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection in commercial, industrial, and automotive application.

MECHANICAL DATA

Case: SMPD (TO-263AC)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-M3 - halogen-free, RoHS-compliant

Base P/NHM3 - halogen-free, RoHS-compliant, and

AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 and HM3 suffix meet JESD 201 class 2 whisker test

Polarity: as marked

| MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted) | | | | | |
|--|------------|-------------------------------|-------------|------|--|
| PARAMETER | | SYMBOL | V60DM100C | UNIT | |
| Device marking code | | | V60DM100C | | |
| Maximum repetitive peak reverse voltage | | V _{RRM} | 100 | V | |
| Maximum average forward rectified current (fig. 1) | per device | I _{F(AV)} (1) | 60 | А | |
| | per diode | | 30 | | |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load | | I _{FSM} | 320 | А | |
| Operating junction temperature range | | T _J ⁽²⁾ | -40 to +175 | - °C | |
| Storage temperature range | | T _{STG} | -55 to +175 | | |

Notes

⁽¹⁾ Mounted on infinite heatsink

 $^{^{(2)}}$ The heat generated must be less than the thermal conductivity from junction-to-ambient: $dP_D/dT_J < 1/R_{\theta,JA}$



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| ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted) | | | | | | |
|---|---|-------------------------|-------------------------------|------|------|------|
| PARAMETER | TEST CONDITIONS | | SYMBOL | TYP. | MAX. | UNIT |
| Instantaneous forward voltage per diode | I _F = 5 A | T _A = 25 °C | V _F ⁽¹⁾ | 0.49 | - | - V |
| | I _F = 15 A | | | 0.63 | - | |
| | I _F = 30 A | | | 0.79 | 0.86 | |
| | I _F = 5 A | T _A = 125 °C | VF ('') | 0.40 | - | |
| | I _F = 15 A | | 25 °C | 0.57 | - | |
| | I _F = 30 A | | | 0.70 | 0.78 | |
| Reverse current at rated V _R per diode | $V_R = 70 \text{ V}$ $T_A = 25 \text{ °C}$ $T_A = 125 \text{ °C}$ | | 0.01 | - | | |
| | | T _A = 125 °C | I _R ⁽²⁾ | 5 | - | - mA |
| | V _R = 100 V | T _A = 25 °C | | - | 0.8 | |
| | v _R = 100 v | T _A = 125 °C | | 9 | 25 | |
| Typical junction capacitance | 4.0 V, 1 MHz | | CJ | 2400 | - | pF |

Notes

 $^{(1)}$ Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width $\leq 5 \text{ ms}$

| THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted) | | | | |
|---|----------------------------------|-----------|------|--|
| PARAMETER | SYMBOL | V60DM100C | UNIT | |
| Typical thermal resistance per device | R ₀ JC ⁽¹⁾ | 0.8 | °C/W | |
| | R _{0JA} (2)(3) | 50 | C/VV | |

Notes

- (1) Mounted on infinite heatsink
- (2) The heat generated must be less than the thermal conductivity from junction-to-ambient: $dP_D/dT_J < 1/R_{\theta JA}$ junction-to-ambient
- (3) Free air, without heatsink

| ORDERING INFORMATION (Example) | | | | | |
|--------------------------------|------------------------------|---|---------------|------------------------------------|--|
| PREFERRED P/N | UNIT WEIGHT (g) PACKAGE CODE | | BASE QUANTITY | DELIVERY MODE | |
| V60DM100C-M3/I | 0.55 | I | 2000/reel | 13" diameter plastic tape and reel | |
| V60DM100CHM3/I (1) | 0.55 | I | 2000/reel | 13" diameter plastic tape and reel | |

Note

(1) AEC-Q101 qualified



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RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

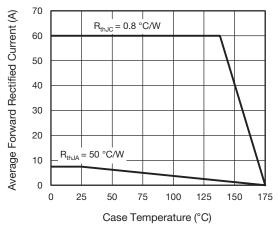


Fig. 1 - Maximum Forward Current Derating Curve

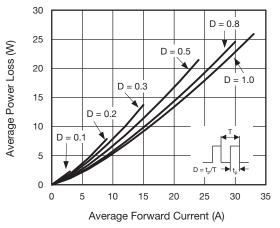


Fig. 2 - Average Power Loss Characteristics

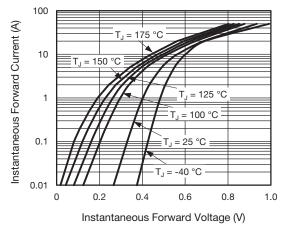


Fig. 3 - Typical Instantaneous Forward Characteristics

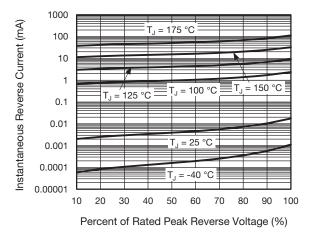


Fig. 4 - Typical Reverse Leakage Characteristics

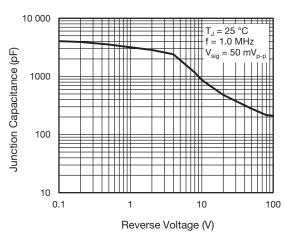


Fig. 5 - Typical Junction Capacitance

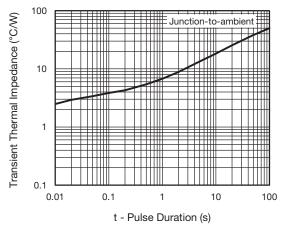


Fig. 6 - Typical Transient Thermal Impedance

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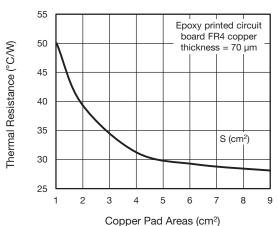
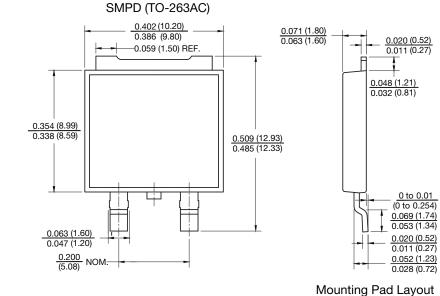
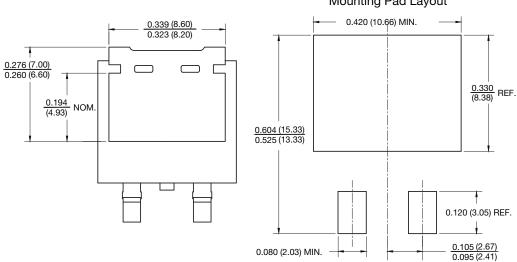


Fig. 7 - Thermal Resistance Junction-to-Ambient vs. Copper Pad Areas

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)







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